

IRF7317PBF

Data Sheet

<u>RFO</u>

Dual N/P-Channel MOSFET, 5.3 A, 6.6 A, 20 V HEXFET, 8-Pin SOIC Infineon

Manufacturers	Infineon Technologies Corporation
Package/Case	SOIC-8
Product Type	Transistors
RoHS	Green
Lifecycle	



Images are for reference only

Please submit RFQ for IRF7317PBF or <u>Email to us: sales@ovaga.com</u> We will contact you in 12 hours.
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General Description

Fifth Generation HEXFETs from International Rectifier utilize advanced processing techniques to achieve extremely low on-resistance per silicon area. This benefit, combined with the fast switching speed and ruggedized device design that HEXFET Power MOSFETs are well known for, provides the designer with an extremely efficient and reliable device for use in a wide variety of applications.

I Generation V TechnologyI Ultra Low On-ResistanceI Dual N and P Channel MOSFETI Surface MountI Fully Avalanche Rated

Features

RoHS Compliant

Low RDS(on)

Dynamic dv/dt Rating

Fast Switching

Dual N and P-Channel MOSFET



Related Products



IRLTS6342TRPBF

Infineon Technologies Corporation TSOP-6



IRF9310PBF

Infineon Technologies Corporation SOIC-8

IRF9358TRPBF

Infineon Technologies Corporation SOP-8



IRFB3307ZPBF

Infineon Technologies Corporation TO-220AB











Infineon Technologies Corporation PQFN2x2DD

IRFH9310TRPBF

Infineon Technologies Corporation PQFN-8

IRFB7430PBF

Infineon Technologies Corporation TO-220

IRF7351TRPBF

Infineon Technologies Corporation SOIC-8